

The $\text{Ag}_2\text{S}-\text{Ga}_2\text{S}_3-\text{As}_2\text{S}_3$ system

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The $\text{Ag}_2\text{S}-\text{Ga}_2\text{S}_3-\text{As}_2\text{S}_3$ system was investigated by differential thermal and X-ray diffraction. The phase diagrams of the systems $\text{Ag}_2\text{S}-\text{As}_2\text{S}_3$, $\text{Ag}_9\text{GaS}_6-\text{Ag}_3\text{AsS}_3$, $\text{AgGaS}_2-\text{AgAsS}_2$, and $\text{AgGaS}_2-\text{Ag}_3\text{AsS}_3$ were constructed, as well as the liquidus surface projection and the isothermal section at 500 K. The interaction in the $\text{Ag}_2\text{S}-\text{As}_2\text{S}_3$ system is eutectic and is described by the equations $L_{e1} \leftrightarrow \text{Ag}_2\text{S} + \text{Ag}_3\text{AsS}_3$ (e_1 : 25 mol.% As_2S_3 , 720 K), $L_{e2} \leftrightarrow \text{AgAsS}_2 + \text{Ag}_3\text{AsS}_3$ (e_2 : 40 mol.% As_2S_3 , 650 K), and $L_{e3} \leftrightarrow \text{AgAsS}_2 + \text{As}_2\text{S}_3$ (e_3 : >99 mol.% As_2S_3 , 580 K). The eutectic point in the $\text{AgGaS}_2-\text{AgAsS}_2$ system lies at 94 mol.% AgAsS_2 , 653 K. The coordinates of the eutectic in the $\text{AgGaS}_2-\text{Ag}_3\text{AsS}_3$ system are 92 mol.% Ag_3AsS_3 , 670 K, and in the $\text{Ag}_9\text{GaS}_6-\text{Ag}_3\text{AsS}_3$ system the eutectic lies at 90 mol.% Ag_3AsS_3 , 687 K.

Phase diagram / Isothermal section / Liquidus surface projection

Introduction

The binary and ternary compounds in the system $\text{Ag}_2\text{S}-\text{Ga}_2\text{S}_3-\text{As}_2\text{S}_3$ possess non-linear optical, acousto-optical, photoelectric, luminescent, and other properties. The silver thiogallate AgGaS_2 belongs to a class of ternary chalcogenides with the chalcopyrite structure. It exhibits high double refraction and a wide transparency region, and is therefore a promising material for quantum electronics [1]. The ternary compounds Ag_3AsS_3 and AgAsS_2 are used as non-linear optical materials [2,3]. As_2S_3 is a glass-forming compound, and therefore glassy materials should exist in the $\text{Ag}_2\text{S}-\text{Ga}_2\text{S}_3-\text{As}_2\text{S}_3$ system.

Three compounds, AgGaS_2 , Ag_9GaS_6 , and $\text{Ag}_2\text{Ga}_{20}\text{S}_{31}$, form in the $\text{Ag}_2\text{S}-\text{Ga}_2\text{S}_3$ system [4-7]. $\text{Ag}_2\text{Ga}_{20}\text{S}_{31}$ forms by a peritectic reaction $L + \text{Ga}_2\text{S}_3 \leftrightarrow \text{Ag}_2\text{Ga}_{20}\text{S}_{31}$ at 1268 K, and has a polymorphous transition at 298 K. AgGaS_2 and Ag_9GaS_6 melt congruently at 1273 K and 1063 K, respectively. Ag_9GaS_6 has a polymorphous transition at 308 K. The phase diagram of the $\text{Ag}_2\text{S}-\text{As}_2\text{S}_3$ system has been investigated in the range 0-50 mol.% As_2S_3 [8]. Two ternary compounds, Ag_3AsS_3 and AgAsS_2 , exist in the system [8-10] and melt congruently at 689 K and 753 K, respectively. According to [11], a glass-formation region was found in the range 100-10 mol.% As_2S_3 of the quasi-binary system $\text{Ag}_2\text{S}-\text{As}_2\text{S}_3$ under the conditions of extremely rapid quenching (cooling rate $\sim 10^6$ K/s).

The phase diagram of the $\text{As}_2\text{S}_3-\text{Ga}_2\text{S}_3$ system was investigated in [12]. No ternary compounds were found, and the sub-solidus region features only the crystallization of the solid solutions of $\text{LT-Ga}_2\text{S}_3$ and As_2S_3 .

Experimental

High-purity elements (silver 99.999 mass%, gallium 99.9997 mass%, sulfur 99.997 mass%) and previously synthesized As_2S_3 (arsenic 99.999 mass%) were used for the synthesis.

All the samples were synthesized in evacuated quartz ampoules with the use of vibration mixing. The temperature in the furnace was raised at a rate of 20-30 K/h to 1100-1200 K. The melts were kept at the maximum temperature for 6 h. The alloys were cooled at the rate of 10-20 K/h to 500 K, and annealed for 600 h to achieve equilibrium state. After annealing, the ampoules were quenched to room temperature into a saturated NaCl solution.

The obtained alloys were investigated by differential thermal analysis (DTA) and X-ray diffraction (XRD). DTA was performed with a set-up consisting of a Thermodent furnace, PDA-1 XY-recorder, and a thermocouple amplifier block. The temperature was controlled by a Pt/Pt-Rh thermocouple. Uniform heating of the furnace was programmed at the rate of 10 K/min, with inertial cooling. Powder diffraction patterns were recorded on

a DRON 4-13 diffractometer with $\text{CuK}\alpha$ -radiation in the 10 – 80° 2θ range, with 0.05° scan step and 1 s exposure at each point. Powder Cell 2.3 software was used for the X-ray phase analysis.

Results and discussion

As the Ag_2S – As_2S_3 phase diagram had only been investigated in the range 0 – 50 mol.% As_2S_3 [8], a re-investigation of the system covering the entire concentration range was performed (Fig. 1). The existence of the two ternary compounds, Ag_3AsS_3

and AgAsS_2 , which both melt congruently, was confirmed. The interaction of the components and the ternary compounds is described by the following equations: $L_{e1} \leftrightarrow \text{Ag}_2\text{S} + \text{Ag}_3\text{AsS}_3$ ($e_1 = 25$ mol.% As_2S_3 , 720 K), $L_{e2} \leftrightarrow \text{AgAsS}_2 + \text{Ag}_3\text{AsS}_3$ ($e_2 = 40$ mol.% As_2S_3 , 650 K), and $L_{e3} \leftrightarrow \text{AgAsS}_2 + \text{As}_2\text{S}_3$ (580 K). The temperature of the latter process is only slightly lower than the melting point of As_2S_3 (583 K), therefore this eutectic is degenerate.

The phase diagram of the AgGaS_2 – AgAsS_2 section was investigated in the entire concentration range (Fig. 2).

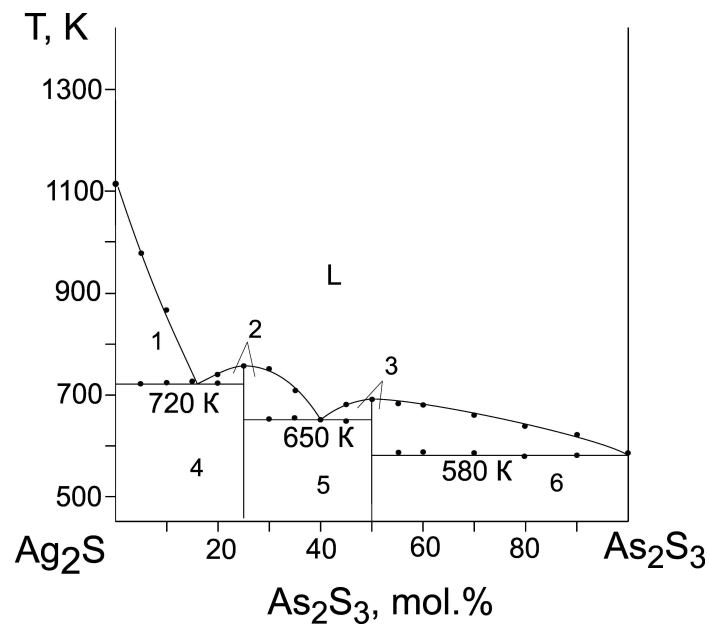


Fig. 1 Phase diagram of the Ag_2S – As_2S_3 system.

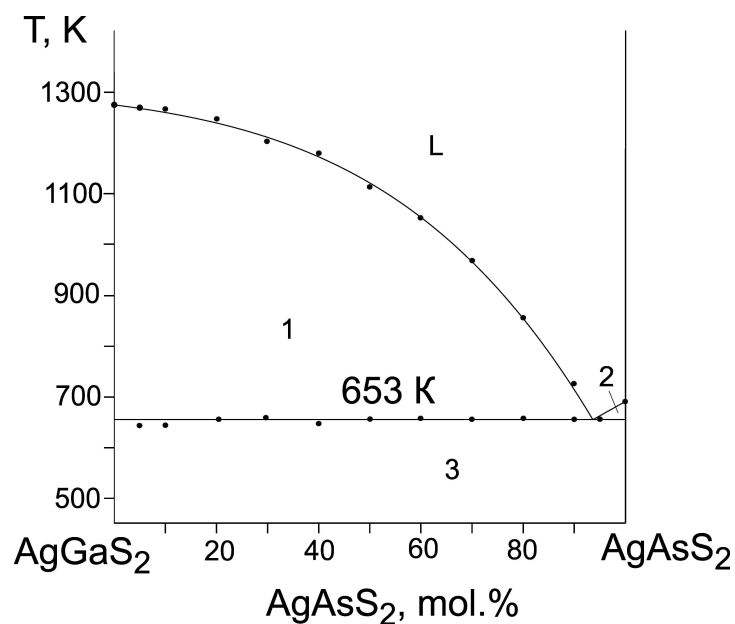


Fig. 2 Phase diagram of the AgGaS_2 – AgAsS_2 system.

The results show that the system is of the eutectic type. The coordinates of the eutectic, determined by the construction of a Tamman triangle, are 94 mol.% AgAsS_2 , 653 K. The solid solubility in the components is negligible.

The phase diagrams of the sections $\text{AgGaS}_2-\text{Ag}_3\text{AsS}_3$ and $\text{Ag}_9\text{GaS}_6-\text{Ag}_3\text{AsS}_3$ are similar, since both of them are of the eutectic type. The eutectic coordinates are 92 mol.% Ag_3AsS_3 , 670 K for the $\text{AgGaS}_2-\text{Ag}_3\text{AsS}_3$ system, and 90 mol.% Ag_3AsS_3 , 687 K for the $\text{Ag}_9\text{GaS}_6-\text{Ag}_3\text{AsS}_3$ system.

The phase diagram of the $\text{Ag}_2\text{Ga}_{20}\text{S}_{31}-\text{As}_2\text{S}_3$ system (Fig. 3) is quasi-binary in the sub-solidus region. The liquidus line consists of the three curves of primary crystallization of $\alpha\text{-Ga}_2\text{S}_3$ (field 2), $\beta\text{-Ga}_2\text{S}_3$ (field 4) and As_2S_3 (field 8). The sub-liquidus part features lines that correspond to the beginning of the secondary crystallization of $\text{L} + \beta\text{-Ga}_2\text{S}_3 + \text{Ag}_2\text{Ga}_{20}\text{S}_{31}$ (in the peritectic reaction $\text{L} + \beta\text{-Ga}_2\text{S}_3 \leftrightarrow \text{Ag}_2\text{Ga}_{20}\text{S}_{31}$) and $\text{L} + \beta\text{-Ga}_2\text{S}_3 + \text{As}_2\text{S}_3$ (in the eutectic reaction $\text{L} \leftrightarrow \beta\text{-Ga}_2\text{S}_3 + \text{As}_2\text{S}_3$). The solid solubility in the components does not exceed 2 mol.%. The solidus is a horizontal line at 579 K, which belongs to the plane of the non-variant peritectic process $\text{L} + \beta\text{-Ga}_2\text{S}_3 \leftrightarrow \text{As}_2\text{S}_3 + \text{Ag}_2\text{Ga}_{20}\text{S}_{31}$.

The isothermal section of the $\text{Ag}_2\text{S}-\text{Ga}_2\text{S}_3-\text{As}_2\text{S}_3$ system at 500 K is presented in Fig. 4. All the phases existing at this temperature are in the solid state.

No quaternary compounds were found in the system. There are six three-phase fields, separated by five two-phase equilibria.

The liquidus surface projection of the $\text{Ag}_2\text{S}-\text{Ga}_2\text{S}_3-\text{As}_2\text{S}_3$ system is shown in Fig. 5. The system consists of five sub-systems: $\text{Ag}_2\text{S}-\text{Ag}_9\text{GaS}_6-\text{Ag}_3\text{AsS}_3$, $\text{Ag}_9\text{GaS}_6-\text{AgGaS}_2-\text{Ag}_3\text{AsS}_3$, $\text{AgGaS}_2-\text{AgAsS}_2-\text{Ag}_3\text{AsS}_3$, $\text{AgGaS}_2-\text{AgAsS}_2-\text{As}_2\text{S}_3$, and $\text{AgGaS}_2-\text{Ga}_2\text{S}_3-\text{As}_2\text{S}_3$, which may be viewed as independent.

The liquidus of the four sub-systems (except $\text{AgGaS}_2-\text{Ga}_2\text{S}_3-\text{As}_2\text{S}_3$) consists of the three curves of primary crystallization of the components that form the sub-system. The liquidus of the $\text{AgGaS}_2-\text{Ga}_2\text{S}_3-\text{As}_2\text{S}_3$ system consists of the five fields of primary crystallization of AgGaS_2 , $\alpha\text{-Ga}_2\text{S}_3$, $\beta\text{-Ga}_2\text{S}_3$, $\text{Ag}_2\text{Ga}_{20}\text{S}_{31}$, and As_2S_3 . The temperature of the ternary eutectic E_5 in the $\text{AgGaS}_2-\text{AgAsS}_2-\text{As}_2\text{S}_3$ sub-system is 577 K, which differs only insignificantly from the eutectics in the systems $\text{AgAsS}_2-\text{As}_2\text{S}_3$ (580 K), $\text{AgGaS}_2-\text{As}_2\text{S}_3$ (582 K), and slightly more from that of the system $\text{AgGaS}_2-\text{AgAsS}_2$ (653 K). Analogous situations are observed for the non-variant points E_4 and P_2 . The As_2S_3 content of the non-variant points E_4 , E_5 , P_2 is 98 mol.% As_2S_3 , which complicates the preparation of crystalline samples of this composition and hence the investigation of the phase diagram in this part of the system (see enlargement in Fig. 5).

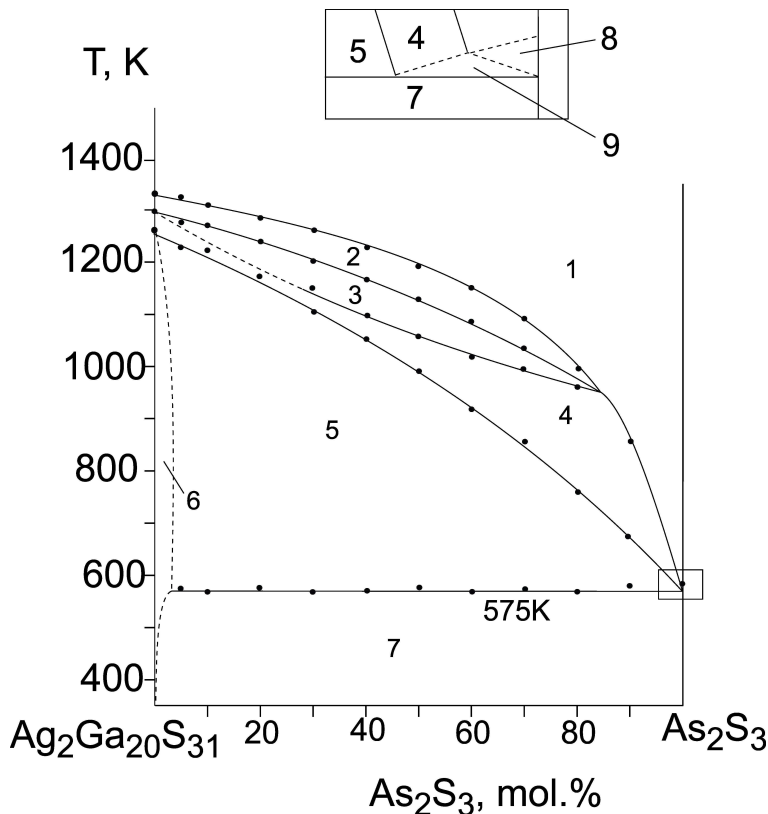


Fig. 3 Phase diagram of the $\text{Ag}_2\text{Ga}_{20}\text{S}_{31}-\text{As}_2\text{S}_3$ system.

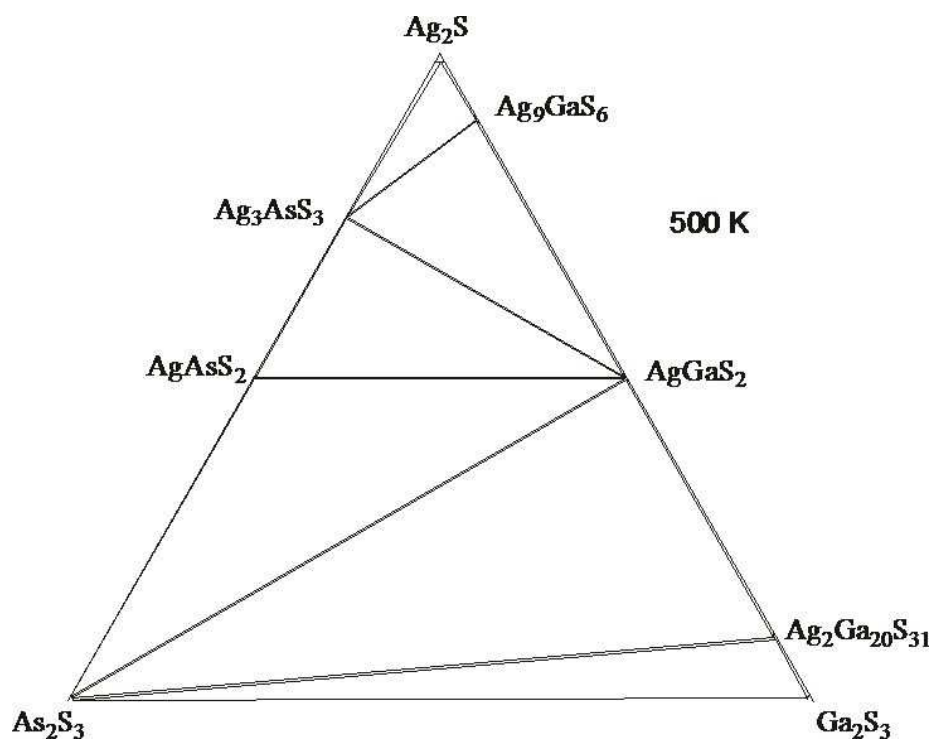


Fig. 4 Isothermal section of the Ag_2S – Ga_2S_3 – As_2S_3 system at 500 K.

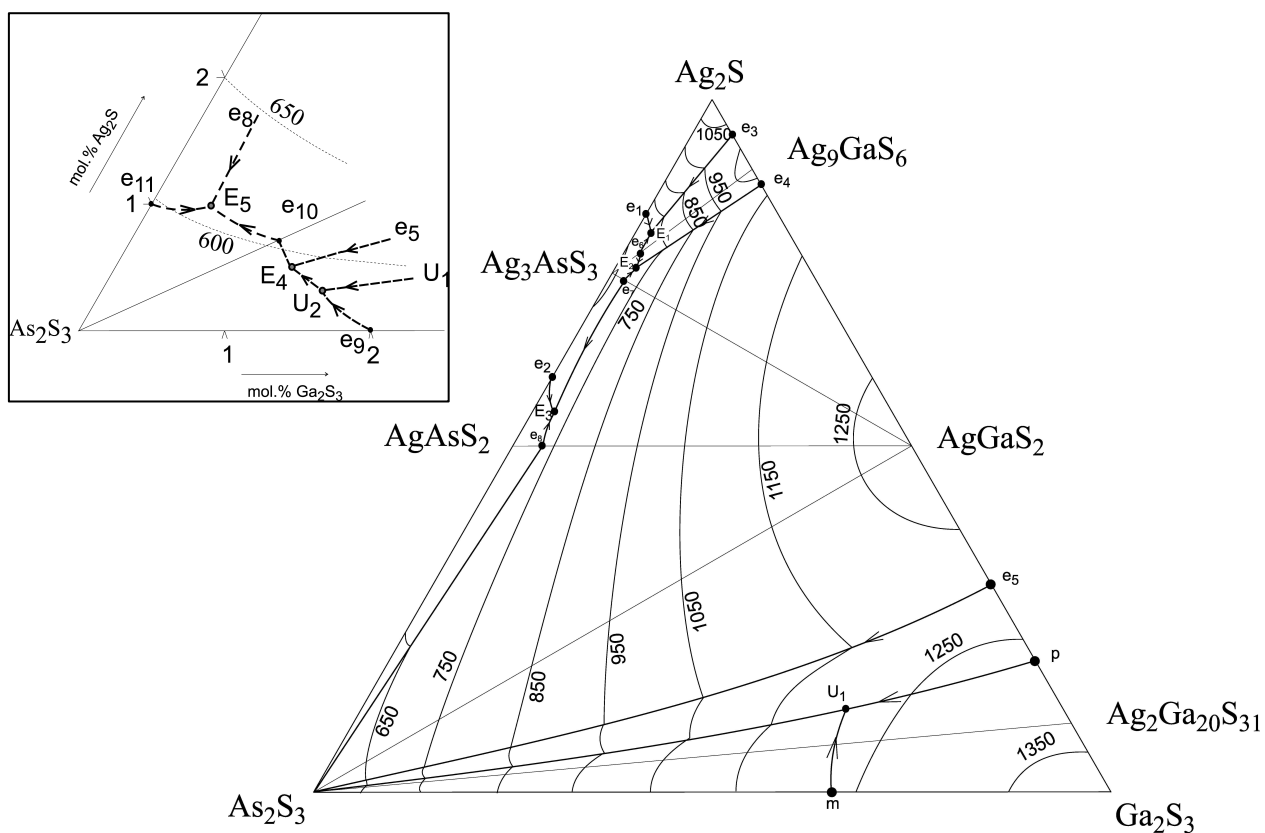


Fig. 5 Liquidus surface projection of the Ag_2S – Ga_2S_3 – As_2S_3 system.

Conclusions

Based on the results of X-ray diffraction and differential thermal analysis, we investigated the phase diagrams of the systems $\text{Ag}_2\text{S}-\text{As}_2\text{S}_3$, $\text{Ag}_9\text{GaS}_6-\text{Ag}_3\text{AsS}_3$, $\text{AgAsS}_2-\text{AgGaS}_2$, and $\text{AgGaS}_2-\text{Ag}_3\text{AsS}_3$, as well as the liquidus surface projection and the isothermal section at 500 K of the $\text{Ag}_2\text{S}-\text{Ga}_2\text{S}_3-\text{As}_2\text{S}_3$ system. The nature and temperature of the non-variant and monovariant processes were determined.

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